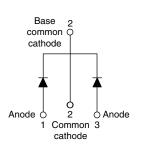


VS-20CTQ150PbF, VS-20CTQ150-N3

Vishay Semiconductors

Schottky Rectifier, 2 x 10 A

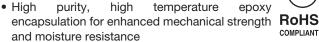


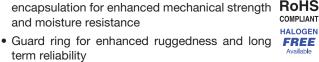


PRODUCT SUMMARY	
Package	TO-220AB
I _{F(AV)}	2 x 10 A
V_R	150 V
V _F at I _F	0.66 V
I _{RM} max.	5 mA at 125 °C
T _J	175 °C
Diode variation	Common cathode
E _{AS}	2.45 mJ

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High frequency operation







- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

The center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AN	D CHARACTERISTICS		
SYMBOL	CHARACTERISTICS	VALUES	UNITS
I _{F(AV)}	Rectangular waveform	20	Α
V _{RRM}		150	V
I _{FSM}	t _p = 5 μs sine	1030	Α
V _F	10 A _{pk} , T _J = 125 °C (per leg)	0.66	V
T _J	Range	- 55 to 175	°C

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-20CTQ150PbF	VS-20CTQ150-N3	UNITS		
Maximum DC reverse voltage	V _R	150	150	V		
Maximum working peak reverse voltage	V _{RWM}	150	150	V		

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS		
Maximum average per leg		50 % duty cycle at T _C = 154 °C	rectangular waveform	10	Α		
See fig. 5 per device	I _{F(AV)}	30 % duty cycle at 16 = 134 C	o, rectangular wavelonn	20	A		
Maximum peak one cycle		5 μs sine or 3 μs rect. pulse	Following any rated load	1030			
non-repetitive surge current per leg See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	180	А		
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 0.7 A, L = 10 mH		2.45	mJ		
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to ze Frequency limited by T _J maxim		0.7	А		



VS-20CTQ150PbF, VS-20CTQ150-N3

Vishay Semiconductors

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS			UNITS	
		10 A	T ₁ = 25 °C	0.80	0.88		
Maximum forward voltage drop per leg	V (1)	20 A	- I _J = 25 °C	0.90	1.0	V	
See fig. 1	V _{FM} ⁽¹⁾	10 A	T _{.1} = 125 °C	0.63	0.66		
		20 A	1j = 125 C	0.73	0.77		
Maximum reverse leakage current per leg	I	T _J = 25 °C	V _B = Rated V _B	3.0	25	μΑ	
See fig. 2	I _{RM}	T _J = 125 °C	VR = nateu VR	2.7	5.0	mA	
Typical junction capacitance per leg	C _T	$V_R = 5 \ V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		-	280	pF	
Typical series inductance per leg	L _S	Measured lead to lead 5 mm from package body		-	8.0	nH	
Maximum voltage rate of change	dV/dt	Rated V _R		-	10 000	V/µs	

Note

 $^{^{(1)}\,}$ Pulse width $<300~\mu s,$ duty cycle <2~%

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range	je	T _J , T _{Stg}		- 55 to 175	°C		
Maximum thermal resistance junction to case per leg	,	В	DC operation	2.0			
Maximum thermal resistance junction to case per package	•	R _{thJC}	DC operation	1.0	°C/W		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased (Only for TO-220)	0.50			
Approximate weight				2	g		
Approximate weight				0.07	OZ.		
Mounting torque	minimum			6 (5)	kgf · cm		
Mounting torque —	maximum			12 (10)	(lbf \cdot in)		
Marking device			Case style TO-220AB	20CT	Q150		



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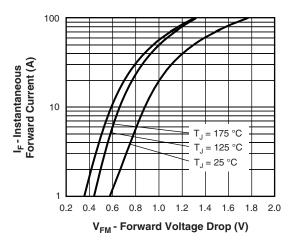


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

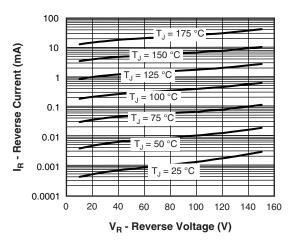


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

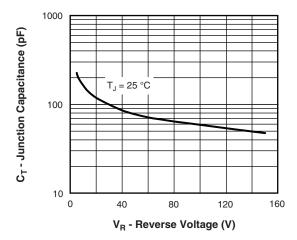


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

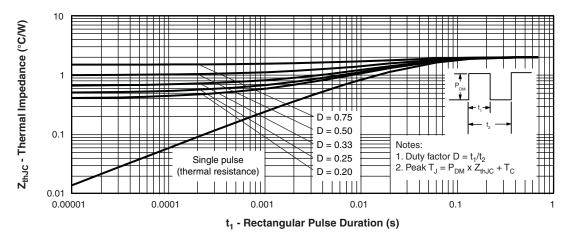


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)



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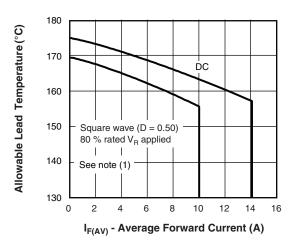


Fig. 5 - Maximum Average Forward Current vs.
Allowable Lead Temperature

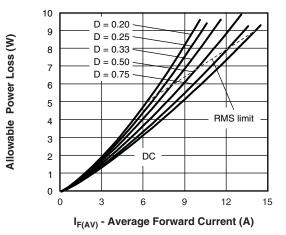


Fig. 6 - Maximum Average Forward Dissipation vs. Average Forward Current

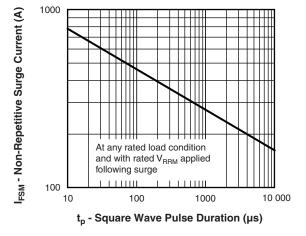


Fig. 7 - Maximum Peak Surge Forward Current vs. Pulse Duration

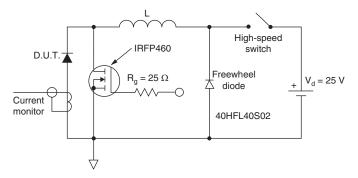


Fig. 8 - Unclamped Inductive Test Circuit

Note

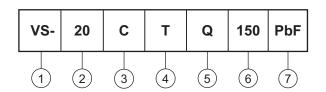
⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80 \%$ rated V_R

VS-20CTQ150PbF, VS-20CTQ150-N3

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

Current rating (20 = 20 A)

3 - Circuit configuration:

C = Common cathode

4 - Package:

T = TO-220

5 - Schottky "Q" series

6 - Voltage ratings (150 = 150 A)

7 - Environmental digit

• PbF = Lead (Pb)-free and RoHS compliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFO	RMATION (Example)		
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-20CTQ150PbF	50	1000	Antistatic plastic tube
VS-20CTQ150-N3	50	1000	Antistatic plastic tube

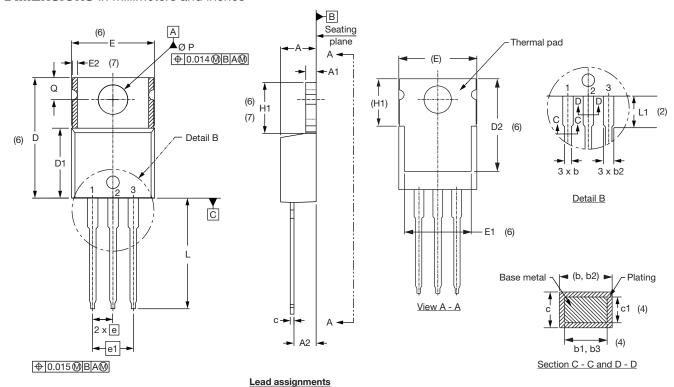
	LINKS TO RELATI	ED DOCUMENTS
Dimensions		www.vishay.com/doc?95222
Dort marking information	TO-220AB PbF	www.vishay.com/doc?95225
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028



Vishay Semiconductors

TO-220AB

DIMENSIONS in millimeters and inches



Diodes

- 1. Anode/open 2. - Cathode
- 3. Anode

Conforms to JEDEC outline TO-220AB

MILLIMETERS

MILLIM	IETERS	INC	INCHES		
MIN.	MAX.	MIN.	MAX.	NOTES	
4.25	4.65	0.167	0.183		
1.14	1.40	0.045	0.055		
2.56	2.92	0.101	0.115		
0.69	1.01	0.027	0.040		
0.38	0.97	0.015	0.038	4	
1.20	1.73	0.047	0.068		
1.14	1.73	0.045	0.068	4	
0.36	0.61	0.014	0.024		
0.36	0.56	0.014	0.022	4	
14.85	15.25	0.585	0.600	3	
8.38	9.02	0.330	0.355		
11.68	12.88	0.460	0.507	6	
	MIN. 4.25 1.14 2.56 0.69 0.38 1.20 1.14 0.36 0.36 14.85 8.38	4.25 4.65 1.14 1.40 2.56 2.92 0.69 1.01 0.38 0.97 1.20 1.73 1.14 1.73 0.36 0.61 0.36 0.56 14.85 15.25 8.38 9.02	MIN. MAX. MIN. 4.25 4.65 0.167 1.14 1.40 0.045 2.56 2.92 0.101 0.69 1.01 0.027 0.38 0.97 0.015 1.20 1.73 0.047 1.14 1.73 0.045 0.36 0.61 0.014 0.36 0.56 0.014 14.85 15.25 0.585 8.38 9.02 0.330	MIN. MAX. MIN. MAX. 4.25 4.65 0.167 0.183 1.14 1.40 0.045 0.055 2.56 2.92 0.101 0.115 0.69 1.01 0.027 0.040 0.38 0.97 0.015 0.038 1.20 1.73 0.047 0.068 1.14 1.73 0.045 0.068 0.36 0.61 0.014 0.024 0.36 0.56 0.014 0.022 14.85 15.25 0.585 0.600 8.38 9.02 0.330 0.355	

SYMBOL	IVIILLIIV	MILLIME I ENO INCRES		NOTES	
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° t	o 93°	90° t	o 93°	

INCHES

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- Thermal pad contour optional within dimensions E, H1, D2 and
- $^{(7)}$ Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

Lead tip



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Vishay

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